PRODU	JCTS		TYPE				PAGE
	Semicor	nductor IC		BD60	)61GU	т	1
Structure	Silicon Mor	olithic Integ	rated Circ	cuit			
Product Name		-			onverter	for mobile phone	
				20,200			
Туре	BD606	61GUT	•				
Features	-	us rectificati I schottky di			onverter		
OAbsolute Maximum Ratings (	Ta=25deg)				<b>-</b>		
Parameter	Symbol		Rating		Unit	Condition	
Maximum applied voltage1	VMAX1		7(*1)		V	VIN, EN, VFB, TE	ST
Maximum applied voltage2	VMAX2		20(*1)		V	SW , VOUT	
Power dissipation	Pd		800(*2)		mW		
Operating temperature range	Topr		30 to +85		deg		
Storage temperature range (*1) These values are based o	Tstg		55 to +150	)	deg		
	nditions (Ta=	-30 to +85d					
ORecommended operating cor Parameter	nditions (Ta=	-30 to +850 Min.	leg) Rating Typ.	Max.	Unit	Conditio	n
Parameter Supply voltage This product isn't designed to p Status of this document	Symbol Vin	Min. 2.7 against radi	Rating Typ. 3.6	5.5	Unit V	Conditio	n
Parameter Supply voltage This product isn't designed to p Status of this document The English version of this document is t A customer may use this translation vers If there are any differences in translation	Symbol Vin protect itself the formal spec- sion only for a re- version of this	Min. 2.7 against radi	Rating Typ. 3.6 0 active ray o reading the al version tak	5.5 yS. formal version kes priority.	n.		
Parameter Supply voltage This product isn't designed to p Status of this document The English version of this document is t A customer may use this translation vers If there are any differences in translation	Symbol Vin protect itself is the formal spec- sion only for a re- version of this version of this version of this version of this se version of this se designed ions devices, of the equipment of as medical ins se be sure to co of any circu om patent infri	Min. 2.7 against radi ification. eference to help document, form document, form to be used wi electrical appli or devices wh struments, trai onsult with ou its described	Rating Typ. 3.6 0 active rate o reading the al version take th ordinary of iances, and ich require a insportation or sales repr	5.5 yS. eformal version kes priority. electronic eq electronic toy an extremely equipment, a resentative in	vipment of ys). high leve erospace advance.	or devices (such as audio el of reliability and the m machinery, nuclear-reac	o-visual equip alfunction of
Parameter Supply voltage This product isn't designed to p Status of this document The English version of this document is t A customer may use this translation vers If there are any differences in translation If the are are any differences in	Symbol Vin protect itself is the formal spec- sion only for a re- version of this version of this version of this version of this se version of this is designed ions devices, of the equipment of as medical ing se be sure to co e of any circu oom patent infri	Min. 2.7 against radi	Rating Typ. 3.6 0 active ray o reading the al version tak th ordinary of iances, and ich require a insportation ir sales repri- herein, con	5.5 yS. eformal version kes priority. electronic eq electronic toy an extremely equipment, a resentative in	vipment o ys). high leve erospace advance. nse unde	or devices (such as audio el of reliability and the m e machinery, nuclear-reac er any patent or other ri	o-visual equip alfunction of tor controller ght, and mak

R	H	FT	

## **OElectrical Characteristics**

(Unless otherwise noted, Ta = -30 to +85deg, Vin=3.6V)

Deverator	Symbol	Spec			Unit	Condition	
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
EN Terminal					-1		
EN Low threshold voltage	VthL	-	-	0.4	v		
EN High threshold voltage	VthH	1.4	-	-	v		
EN Input current	lin	-	18.3	30	uA	EN=5.5V	
EN Output current	lout	-2	-0.1	-	uA	EN=0	
Switching Regulator						······································	
Input voltage range	Vin	3.1	-	5.5	v		
Quiescent Current	lq	-	0.1	2	uA	EN=0V	
Current Consumption	ldd	-	4.3	5.8	mA	EN=2.6V,VFB=1.0V,VIN=3.6V	
Feedback voltage	Vfb	0.47	0.5	0.53	v		
Inductor current limit	lcoil	270	350	430	mA	Vin=3.6V (*1)	
SW saturation voltage	Vsat	-	0.3	0.8	v	Isw=200mA,Vout=13V	
SW on resistance P	Ronp	-	4	8	Ohm	lpch=200mA,Vout=13V	
Switching frequency	fSW	0.8	1.0	1.2	MHz		
Duty cycle limit	Duty	82.7	85	-	%	VFB=0V	
Output voltage range	Vo	-	-	18	v		
Over voltage limit	Ovl	18	18.5	19	v	VFB=0V	
Start up time	Ts	-	0.5	1.0	ms		

\*1. This parameter is tested with dc measurement.

REV. :

R	Η	

BD6061GUT

OTerminals

C3

TYPE

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OExternal dimensions





BALL	BALL Name
A1	GNDA
A2	EN
A3	TEST
B1	VIN
B3	VFB
C1	VOUT
C2	SW

GND



VCSP60N1(8Pin) (Unit:mm)





○ Cautions on use

RDH

(1) Absolute Maximum Ratings

An excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down devices, thus making impossible to identify breaking mode such as a short circuit or an open circuit. If any special mode exceeding the absolute maximum ratings is assumed, consideration should be given to take physical safety measures including the use of fuses, etc.

TYPE

(2) Power supply and GND line

Design PCB pattern to provide low impedance for the wiring between the power supply and the GND lines. Pay attention to the interference by common impedance of layout pattern when there are plural power supplies and GND lines. Especially, when there are GND pattern for small signal and GND pattern for large current included the external circuits, please separate each GND pattern. Furthermore, for all power supply terminals to ICs, mount a capacitor between the power supply and the GND terminal. At the same time, in order to use a capacitor, thoroughly check to be sure the characteristics of the capacitor to be used present no problem including the occurrence of capacity dropout at a low temperature, thus determining the constant.

(3) GND voltage

Make setting of the potential of the GND terminal so that it will be maintained at the minimum in any operating state. Furthermore, check to be sure no terminals are at a potential lower than the GND voltage including an actual electric transient.

(4) Short circuit between terminals and erroneous mounting

In order to mount ICs on a set PCB, pay thorough attention to the direction and offset of the ICs. Erroneous mounting can break down the ICs. Furthermore, if a short circuit occurs due to foreign matters entering between terminals or between the terminal and the power supply or the GND terminal, the ICs can break down.

- (5) Operation in strong electromagnetic field
- Be noted that using ICs in the strong electromagnetic field can malfunction them.
- (6) Input terminals

In terms of the construction of IC, parasitic elements are inevitably formed in relation to potential. The operation of the parasitic element can cause interference with circuit operation, thus resulting in a malfunction and then breakdown of the input terminal. Therefore, pay thorough attention not to handle the input terminals, such as to apply to the input terminals a voltage lower than the GND respectively, so that any parasitic element will operate. Furthermore, do not apply a voltage to the input terminals when no power supply voltage is applied to the IC. In addition, even if the power supply voltage is applied, apply to the input terminals a voltage lower than the power supply voltage or within the guaranteed value of electrical characteristics.

(7) External capacitor

In order to use a ceramic capacitor as the external capacitor, determine the constant with consideration given to a degradation in the nominal capacitance due to DC bias and changes in the capacitance due to temperature, etc.

(8) Thermal shutdown circuit (TSD)

When junction temperatures become 175°C (typ) or higher, the thermal shutdown circuit operates and turns a switch OFF. The thermal shutdown circuit, which is aimed at isolating the LSI from thermal runaway as much as possible, is not aimed at the protection or guarantee of the LSI. Therefore, do not continuously use the LSI with this circuit operating or use the LSI assuming its operation.

(9) Thermal design

Perform thermal design in which there are adequate margins by taking into account the permissible dissipation (Pd) in actual states of use.

## (10) DC/DC converter

Please select the low DCR inductors to decrease power loss for DC/DC converter.

Α

REV. :

	TYPE Information for board assembly	PAGE
Semiconductor IC	BD6061GUT	1/10
— Information for board Package : VCSP60N1	assembly —	
<ul> <li>(A table of contents)</li> <li>1. Construction and materials</li> <li>2. External dimensions</li> <li>3. Reference land terminal area</li> <li>4. Recommend soldering conditions</li> <li>5. Packing specification</li> <li>6. Store products and allowance time to monoportal formation of marking lot number</li> <li>8. Regarding the underfill material</li> </ul>	$2/10 \text{ page} \\ 3/10 \text{ page} \\ 4/10 \sim 5/10 \text{ page} \\ 5/10 \sim 9/10 \text{ page} \\ 10/10  pa$	
9. Note		

## 1. Construction and materials





No.	Part Name	Materials(Method)
1.	Die	Silicon
2.	Cu Layer	Cu
3.	Cu Post	Cu
4.	Encapsuration	Epoxy Resin
5.	Solder Ball	Sn-3.0Ag-0.5Cu Solder
6.	Encapsuration	Polyamide−imide Resin
7.	Marking	Laser Marking

A dry weight per one device : 0.003g

DESIGN Inasaki	CHECK Koji	APPROVAL Mutsura	DATE: 06.Apr.2005	SPECIFICATION No. : TSZ02201-BD6061GUT-1-2
	Taniuchí 6. Apr.2005	Daji	REV. A	ROHM CO.,LTD.



	PRODUCTS	TYPE Information for board assembly	PAGE
	Semiconductor IC	BD6061GUT	3×10
3. Reference land termi			0/10
	Reference	(Unit:mm) Reference	
	symbol	value	
	e	0.50	
	b3	0.25	
conditions, s		land terminal area to consideration flux cleaning reen mask tolerance,bridge,	
ROHM CO.,LTD.	REV. A	SPECIFICATION No. : TSZ02201-BD6061GUT-	1-2
			. 2
TSZ22111.04			





ROHM CO.,LTD.





Figure10. Label marking

ROHM CO.,LTD. REV. A SPECIFICATION No. : TSZ02201-BD6061GUT-1-2

## TSZ22111.04



		PRODUCTS		TYPE In	formation for board assembly	PAGE
	JHII		conductor IC		BD6061GUT	9/10
	Packing materia he used packing	s	are mentioned as	below.		
	The name of m	aterials	The quality of the	materials		
	Таре		PS		•	
	Cover tape		APET + PE			
	Reel		PS			
	Inner box		Card board	box		
	Packing box		Card board	box		
5. 8 A ( Peelin;	Please refer to F g direction Peelir 300mm±10 9. 2. Failure rate The missing parts 1) Continuous m 2) Discontinuous	n of cover Figure 13 for mg speed mm/min F in taping issing is 0 missing is	tape is 0.2~0.7N or evaluation meth Figure 13. The mether is.	165	5~180°	
ROH	M CO.,LTD.	REV. A		SPECIFIC	ATION No. : TSZ02201-BD6061GUT-1	-2
TS72211						_

TSZ22111-04

